1. Safety Precautions

1-1. Repair Precaution

Before attempting any repair or detailed tuning, shield the device from RF noise or static electricity discharges.

Use only demagnetized tools that are specifically designed for small electronic repairs, as most electronic parts are sensitive to electromagnetic forces.

Use only high quality screwdrivers when servicing products. Low quality screwdrivers can easily damage the heads of screws.

Use only conductor wire of the properly gauge and insulation for low resistance, because of the low margin of error of most testing equipment.
We recommend 22-gauge twisted copper wire.

Hand-soldering is not recommended, because printed circuit boards (PCBs) can be easily damaged, even with relatively low heat. Never use a soldering iron with a power rating of more than 100 watts and use only lead-free solder with a melting point below 250°C (482°F).

Prior to disassembling the battery charger for repair, ensure that the AC power is disconnected.
Always use the replacement parts that are registered in the SEC system. Third-party replacement parts may not function properly.

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1. Safety Precautions

1-2. ESD(Electrostatically Sensitive Devices) Precaution

Many semiconductors and ESDs in electronic devices are particularly sensitive to static discharge and can be easily damaged by it. We recommend protecting these components with conductive anti-static bags when you store or transport them.

Always use an anti-static strap or wristband and remove electrostatic buildup or dissipate static electricity from your body before repairing ESDs.

Ensure that soldering irons have AC adapter with ground wires and that the ground wires are properly connected.

Use only desoldering tools with plastic tips to prevent static discharge.

Properly shield the work environment from accidental electrostatic discharge before opening packages containing ESDs.

The potential for static electricity discharge may be increased in low humidity environments, such as air-conditioned rooms. Increase the airflow to the working area to decrease the chance of accidental static electricity discharges.

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2. Specification

2-1. GSM General Specification

Item		GSM 850	EGSM 900	DCS1800	PCS1900
Freq. Band[MHz] Uplink/Downlink		824~849 869~894	880~915 925~960	1710~1785 1805~1880	1850~1910 1930~1990
ARFCN range		128~251	0~124 & 975~1023	512~885	512~810
Tx/Rx spacing		45MHz	45MHz	95MHz	80MHz
Mod. Bit rate/ Bit Period		270.833kbps 3.692us	270.833kbps 3.692us	270.833kbps 3.692us	270.833kbps 3.692us
Time Slot Period/ Frame Period		576.9us 4.615ms	576.9us 4.615ms	576.9us 4.615ms	576.9us 4.615ms
Modulation	GSM/ EGPRS	GMSK/ 8PSK	GMSK/ 8PSK	GMSK/ 8PSK	GMSK/ 8PSK
MS Power		33dBm~5dBm	33dBm~5dBm	30dBm~0dBm	30dBm~0dBm
Power Class		4(GMSK) E2(8PSK)	4(GMSK) E2(8PSK)	1(GMSK) E2(8PSK)	1(GMSK) E2(8PSK)
Sensitivity		-102dBm	-102dBm	-100dBm	-100dBm
TDMA Mux		8	8	8	8

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2. Specification

2-2. GSM Tx Power Class

TX Power control level	GSM850	TX Power control level	EGSM900	TX Power control level	DCS1800	TX Power control level	PCS1900
5	33±2 dBm	5	33±2 dBm	0	30±3 dBm	0	30±3 dBm
6	31±2 dBm	6	31±2 dBm	1	28±3 dBm	1	28±3 dBm
7	29±2 dBm	7	29±2 dBm	2	26±3 dBm	2	26±3 dBm
8	27±2 dBm	8	27±2 dBm	3	24±3 dBm	3	24±3 dBm
9	25±2 dBm	9	25±2 dBm	4	22±3 dBm	4	22±3 dBm
10	23±2 dBm	10	23±2 dBm	5	20±3 dBm	5	20±3 dBm
11	21±2 dBm	11	21±2 dBm	6	18±3 dBm	6	18±3 dBm
12	19±2 dBm	12	19±2 dBm	7	16±3 dBm	7	16±3 dBm
13	17±2 dBm	13	17±2 dBm	8	14±3 dBm	8	14±3 dBm
14	15±2 dBm	14	15±2 dBm	9	12±4 dBm	9	12±4 dBm
15	13±2 dBm	15	13±2 dBm	10	10±4 dBm	10	10±4 dBm
16	11±3 dBm	16	11±3 dBm	11	8±4 dBm	11	8±4 dBm
17	9±3 dBm	17	9±3 dBm	12	6±4 dBm	12	6±4 dBm
18	7±3 dBm	18	7±3 dBm	13	4±4 dBm	13	4±4 dBm
19	5±3 dBm	19	5±3 dBm	14	2±5 dBm	14	2±5 dBm
-	-	-	-	15	0±5 dBm	15	0±5 dBm

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2. Specification

2-3. WCDMA General Specification

Item	WCDMA2100(B1)	WCDMA1900(B2)	WCDMA AWS(B4)	WCDMA850(B5)	WCDMA900(B8)
Freq. Band[MHz] Uplink/Downlink	1920~1980 2110~2170	1850~1910 1930~1990	1710~1755 2110~2155	824~849 869~894	880~915 925~960
ARFCN range	UL：9612~9888 DL：10562~10838	UL：9262~9538 DL：9662~9938	UL：1312~1513 DL：1537~1738	UL：4132~4233 DL：4357~4458	UL：2712~2868 DL：2937~3088
Tx/Rx spacing	190MHz	80MHz	400MHz	45MHz	45MHz
Mod. Bit rate/ Bit Period	42.2Mbps(DL) 5.42Mbps(UL)	42.2Mbps(DL) 5.42Mbps(UL)	42.2Mbps(DL) 5.42Mbps(UL)	42.2Mbps(DL) 5.42Mbps(UL)	42.2Mbps(DL) 5.42Mbps(UL)
Time Slot Period/ Frame Period	WCDMA 10ms/0.667ms HSPA 2ms/0.667ms	WCDMA 10ms/0.667ms HSPA 2ms/0.667ms	WCDMA 10ms/0.667ms HSPA 2ms/0.667ms	WCDMA 10ms/0.667ms HSPA 2ms/0.667ms	WCDMA 10ms/0.667ms HSPA 2ms/0.667ms
Modulation	QPSK 16QAM 64QAM	QPSK 16QAM 64QAM	QPSK 16QAM 64QAM	QPSK 16QAM 64QAM	QPSK 16QAM 64QAM
MS Power (dBm)	25.7 ~ -49(↓)	25.7 ~ -49(↓)	25.7 ~ -49(↓)	25.7 ~ -49(↓)	25.7 ~ -49(↓)
Power Class	3(max+24dBm)	3(max+24dBm)	3(max+24dBm)	3(max+24dBm)	3(max+24dBm)
Sensitivity	-106dBm	-104dBm	-106dBm	-104dBm	-103dBm

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2. Specification

2-4. LTE General Specification

Item	LTE Band1	LTE Band2	LTE Band3	LTE Band4	LTE Band5	LTE Band7
Freq. Band[MHz] Uplink/Downlink	1920~1980 2110~2170	1850~1910 1930~1990	1710~1785 1805~1880	1710~1755 2110~2155	824~849 869~894	2500~2570 2620~2690
ARFCN range	UL:18000~18599 DL:0~599	UL:18600~19199 DL:600~1199	UL:19200~19949 DL:1200~1949	UL:19950~20399 DL:1950~2399	UL:20400~20649 DL:2400~2649	UL:20750~21449 DL:2750~3449
Tx/Rx spacing (MHz)	190	80	95	400	45	120
Channel Bandwidth (MHz)	5/10/15/20	1.4/3/5/10/15/20	1.4/3/5/10/15/20	1.4/3/5/10/15/20	1.4/3/5/10	5/10/15/20
Modulation	QPSK,16/64QAM 256QAM(DL only)	QPSK,16/64QAM 256QAM(DL only)	QPSK,16/64QAM 256QAM(DL only)	QPSK,16/64QAM 256QAM(DL only)	QPSK,16/64QAM 256QAM(DL only)	QPSK,16/64QAM 256QAM(DL only)
MS Power (dBm)	25.7~-39(↓)	25.7~-39(↓)	25.7~-39(↓)	25.7~-39(↓)	25.7~-39(↓)	25.7~-39(↓)
Sensitivity (QPSK, BW 10MHz) (dBm)	-96.3	-94.3	-93.3	-96.3	-94.3	-94.3

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2. Specification

Item	LTE Band8	LTE Band12	LTE Band13	LTE Band17	LTE Band18	LTE Band19
Freq. Band[MHz] Uplink/Downlink	880~915 925~960	699~716 729~746	777~787 746~756	704~716 734~746	815~830 860~875	830~845 875~890
ARFCN range	UL:21450-21799 DL:3450-3799	UL:23010~23179 DL:5010~5179	UL:23180~23279 DL:5180~5279	UL:23730~23849 DL:5730~5849	UL:23850~23999 DL:5850~5999	UL:24000~24149 DL:6000~6149
Tx/Rx spacing (MHz)	45	30	-31	30	45	45
Channel Bandwidth (MHz)	1.4/3/5/10	1.4/3/5/10	1.4/3/5/10	5/10	5/10/15	5/10/15
Modulation	QPSK,16/64QAM 256QAM(DL only)	QPSK,16/64QAM 256QAM(DL only)	QPSK,16/64QAM 256QAM(DL only)	QPSK,16/64QAM 256QAM(DL only)	QPSK,16/64QAM 256QAM(DL only)	QPSK,16/64QAM 256QAM(DL only)
MS Power (dBm)	25.7~-39(↓)	25.7~-39(↓)	25.7~-39(↓)	25.7~-39(↓)	25.7~-39(↓)	25.7~-39(↓)
Sensitivity (QPSK, BW 10MHz) (dBm)	-93.3	-93.3	-93.3	-93.3	-96.3	-96.3

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2. Specification

Item	LTE Band20	LTE Band25	LTE Band26	LTE Band28	LTE Band32	LTE Band38
Freq. Band[MHz] Uplink/Downlink	832~862 791~821	1850~1915 1930~1995	814~849 859~894	703~748 758~803	N/A 1452~1496	2570~2620
ARFCN range	UL:24150~24449 DL:6150~6449	UL:26040~26689 DL:8040~8689	UL:26690~27039 DL:8690~9039	UL:27210~27659 DL:9210~9659	DL:9920~10359	UL/DL:37750 ~ 38249
Tx/Rx spacing (MHz)	-41	80	45	55	N/A	0
Channel Bandwidth (MHz)	5/10/15/20	1.4/3/5/10/15/20	1.4/3/5/10/15	3/5/10/15/20	5/10/15/20	5/10/15/20
Modulation	QPSK,16/64QAM 256QAM(DL only)	QPSK,16/64QAM 256QAM(DL only)	QPSK,16/64QAM 256QAM(DL only)	QPSK,16/64QAM 256QAM(DL only)	QPSK,16/64QAM 256QAM(DL only)	QPSK,16/64QAM 256QAM(DL only)
MS Power (dBm)	25.7~-39(↓)	25.7~-39(↓)	25.7~-39(↓)	25.7~-39(↓)	25.7~-39(↓)	25.7~-39(↓)
Sensitivity (QPSK, BW 10MHz) (dBm))	-93.3	-92.8	-93.8	-94.8	-96.3	-96.3

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2. Specification

Item	LTE Band39	LTE Band40	LTE Band41	LTE Band46	LTE Band66
Freq. Band[MHz] Uplink/Downlink	1880~1920	2300~2400	2496~2690	5150~5925	1710~1780 2110~2200
ARFCN range	UL/DL:38250 ~ 38649	UL/DL:38650 ~ 39649	UL/DL:39650 ~ 41589	UL/DL:46790 ~ 54539	UL:131972 ~ 132671 DL:66436 ~ 67335
Tx/Rx spacing (MHz)	0	0	0	0	400
Channel Bandwidth (MHz)	5/10/15/20	5/10/15/20	5/10/15/20	10/20	1.4/3/5/10/15/20
Modulation	QPSK,16/64QAM 256QAM(DL only)	QPSK,16/64QAM 256QAM(DL only)	QPSK,16/64QAM 256QAM(DL only)	QPSK,16/64QAM 256QAM(DL only)	QPSK,16/64QAM 256QAM(DL only)
MS Power (dBm)	25.7~-39(↓)	25.7~-39(↓)	25.7~-39(↓)	25.7~-39(↓)	25.7~-39(↓)
Sensitivity (QPSK, BW 10MHz) (dBm)	-96.3	-96.3	-94.3	-92.3	-95.8

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2. Specification

2-5. TDSCDMA General Specification

Item	TDSCDMA2010(A)	TDSCDMA1880(F)
Chip rate	1.28 Mcps	1.28 Mcps
OBW	1.6 MHz	1.6 MHz
Freq. Band[MHz] Uplink/Downlink	2010~2025	1880~1920
ARFCN range	10054~10121	9404~9596
Tx/Rx spacing (MHz)	0	0
MS Power (dBm)	25.7 ~ -48(↓)	25.7 ~ -48(↓)
Power Class	2(max+24dBm)	2(max+24dBm)
Sensitivity (dBm /1.28 MHz)	-107.3	-107.3

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3. Product Function

Main Function

Item	Description
OS	Android V8.0
RF	GSM850 / GSM900 / DCS1800 / PCS1900 WCDMA: B1/ B2/ B4/ B5/ B8 TDSCDMA : B34/ B39 LTE: B1/ B2/ B3/ B4/ B5/ B7/ B8/ B12/ B13/ B17/ B18/ B19/ B20/ B25/ B26/ B28/ B32/ B38/ B39/ B40/ B41/ B46/B66
Battery	3500mAh
Base Band	Upto 2.7Ghz + 1.7Ghz
Other RF	A-GPS, Glonass, BEIDOU, Galileo, BT5.0, USB 3.1 Type-C, WIFI 802.11 a/b/g/n/ac MIMO, NFC,MST
Camera	Dual Camera (Wide : 12M Dual A/F, OIS, F1.5-2.4 & Tele : 12M, OIS, F2.4) with LED Flash, 8MP A/F (Front), 5.8MP (IRIS)
Display	6.2", WQHD+, 1440x2960
RAM	6GB
Sensor	Accelerometer, Barometer, Fingerprint Sensor, Gyro Sensor, Geomagnetic Sensor, Hall Sensor, HR Sensor, Iris Sensor, Pressure Sensor, Proximity Sensor, RGB Light Sensor
Accessory	Charger: 5V/2A (AFC: 9V/1.67A) Data cable: 2.8pi, 1.2m(Type C/ USB-A) Ear phone: 3.5pi, 4pin

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